Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Plastic

**Overall Length:** 

0.250 inches

# **Terminal Length:**

0.560 inches

### **Overall Height:**

0.250 inches

**Overall Width:** 

0.185 inches

#### Mounting Method:

Terminal

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

-40.0 breakdown voltage, collector-to-base, emitter open and -40.0 breakdown voltage, collector-to-emitter, base open and -6.0 emitter

to base voltage, static, collector open

## **Current Rating Per Characteristic:**

10.00 milliamperes all primaries

# **Power Rating Per Characteristic:**

310.0 milliwatts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Terminal Type And Quantity:**

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

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